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EMITTING DIODE DEVICE INCLUDING THE
SAME**(30) **Foreign Application Priority Data**

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CPC **H01L 51/0054** (2013.01); **C07D 215/12**
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519/00 (2013.01); **H01L 51/5206** (2013.01)(21) Appl. No.: **14/831,638**(57) **ABSTRACT**(22) Filed: **Aug. 20, 2015**

A pyrene compound and an organic light emitting diode device including the same are disclosed. The organic light emitting diode device includes at least two stacks provided between a first electrode and a second electrode, and a charge generation layer provided between the stacks and including an N type charge generation layer and a P type charge generation layer, wherein the N type charge generation layer is made of the pyrene compound.

Related U.S. Application Data

(63) Continuation of application No. 13/725,400, filed on Dec. 21, 2012, now Pat. No. 9,147,846.

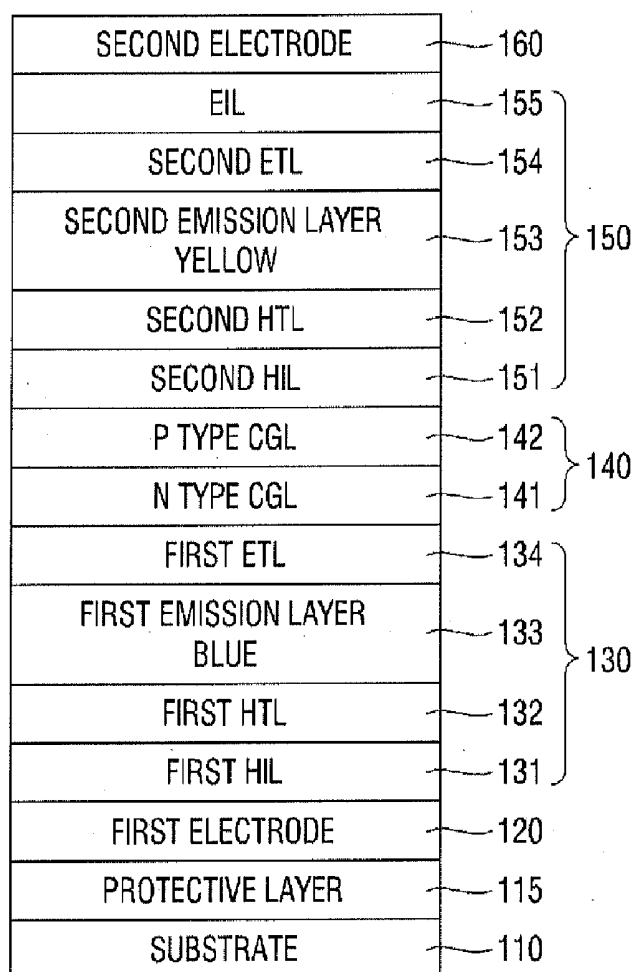


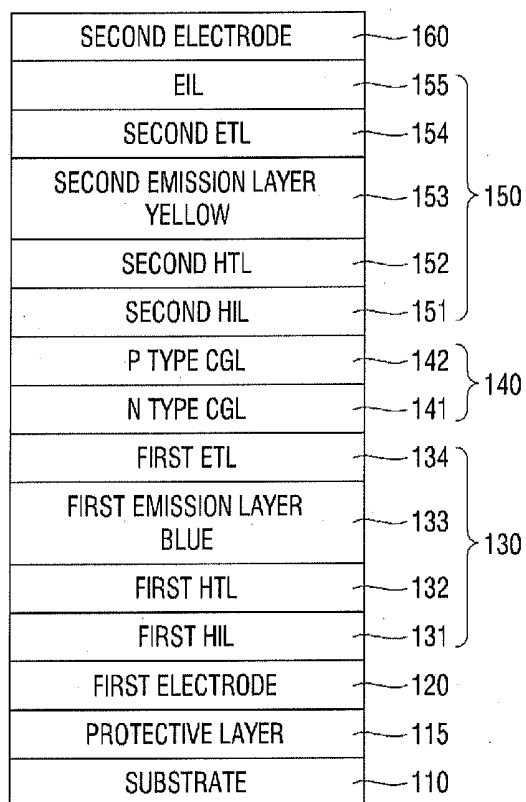
FIG. 1

FIG. 2

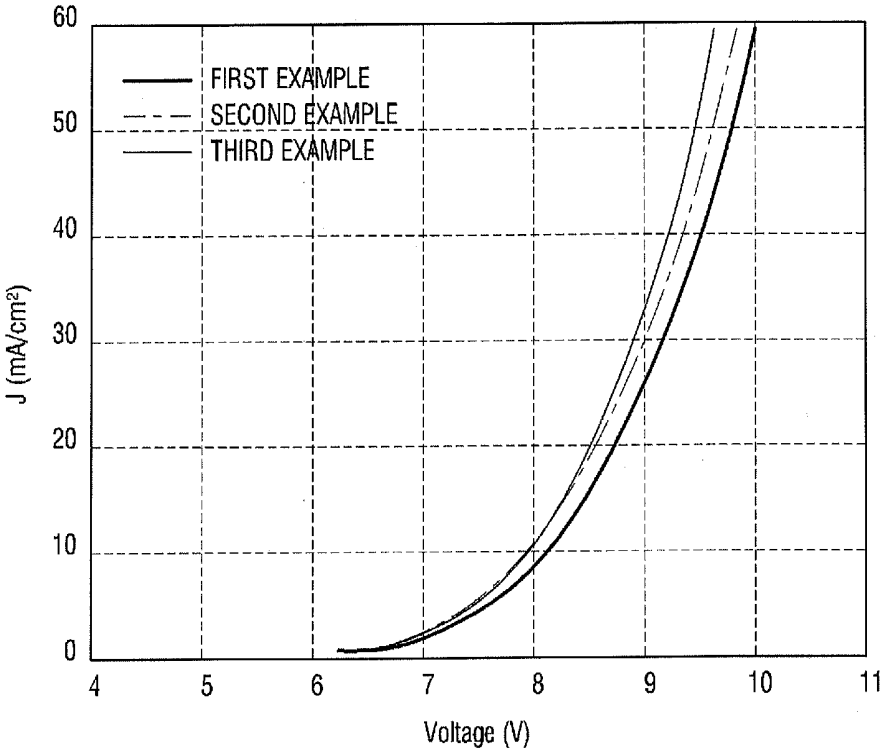
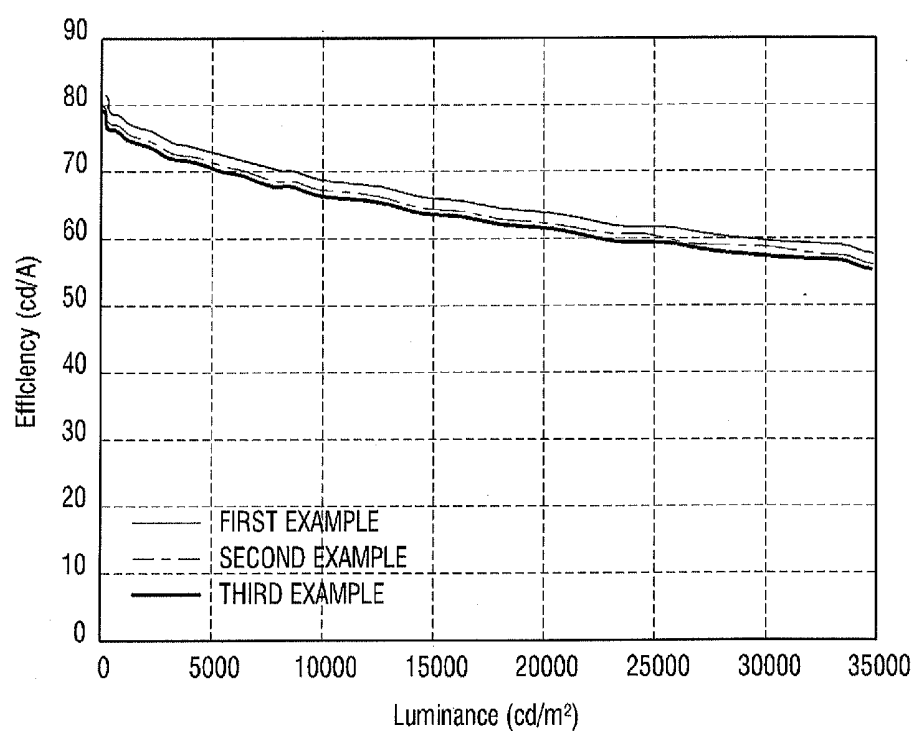


FIG. 3



PYRENE COMPOUND AND ORGANIC LIGHT EMITTING DIODE DEVICE INCLUDING THE SAME

[0001] This application is a continuation application of U.S. patent application Ser. No. 13/725,400, filed on Dec. 21, 2012, which claims the benefit of Korean Patent Application No. 10-2012-0097357 filed on Sep. 3, 2012, which is incorporated herein by reference for all purposes as if fully set forth herein.

BACKGROUND

[0002] 1. Field of the Disclosure

[0003] This document relates to an organic light emitting diode device, and more particularly, to an organic light emitting diode device including a pyrene compound.

[0004] 2. Discussion of the Related Art

[0005] In recent years, with the development of multi-media, the importance of a flat panel display (FPD) has increased. To satisfy the demand, various displays such as a liquid crystal display (LCD), a plasma display panel (PDP), a field emission display (FED), and an organic light emitting diode device have been put to practical use.

[0006] Particularly, the organic light emitting diode device is a self-emissive device, which represents fast response speed of 1 ms or less and low power consumption. Further, since the organic light emitting diode device has an excellent viewing angle, the organic light emitting diode device is beneficial as a moving picture display medium regardless of the size of a device. In addition, since the organic light emitting diode device may be fabricated at a low temperature and a manufacturing process thereof is simple based on an existing semiconductor process technique, it is spotlighted as a next-generation flat panel display.

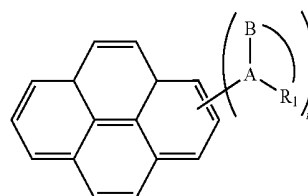
[0007] The organic light emitting diode device includes a cathode, an anode and an organic emission layer interposed between the cathode and the anode. An electron provided from the cathode is combined with a hole provided from the anode at the emission layer to form an exciton. The exciton is transitioned into a ground state from an excited state, thereby emitting light.

[0008] The organic light emitting diode device has been developed as various structures. Among them, a tandem organic light emitting diode device manufacturing by stacking a plurality of emission layers has been developed. The organic light emitting diode device has a plurality of stack structures including a hole injection layer/hole transport layer/emission layer/electron transport layer/electron injection layer. Particularly, a charge generation layer including N type and P type charge generation layers is formed between the stacks, so that a charge is generated or the charge is injected into each emission layer.

[0009] However, in the charge generation layer, an injection characteristic of an electron generated by charge generation at an interfacial surface of a hole injection layer adjacent to a P type charge generation layer due to an energy level difference between an N type charge generation layer and the P type charge generation layer in the N type charge generation layer is deteriorated. When the N type charge generation layer according to the related art is doped with alkaline metal, the alkaline metal is diffused into the P type charge generation layer so that life span of the device is deteriorated.

SUMMARY

[0010] A pyrene compound is represented by the following chemical formula 1:



[Chemical formula 1]

[0011] in the chemical formula 1, the A is one selected from C, N, S, and O, the B and R1 are one selected from a hetero aromatic group having 6 to 24 carbon atoms which includes or does not include a neighboring A, a substituted or unsubstituted aromatic arylamine group, or a substituted or unsubstituted hetero aromatic arylamine group, and the n is an integer in the range of 1 to 4. In another aspect, there is an organic light emitting diode device including at least two stacks provided between a first electrode and a second electrode and a charge generation layer provided between the stacks and including an N type charge generation layer and a P type charge generation layer, wherein the N type charge generation layer is made of the pyrene compound.

BRIEF DESCRIPTION OF THE DRAWINGS

[0012] The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this specification, illustrate embodiments of the invention and together with the description serve to explain the principles of the invention. In the drawings:

[0013] FIG. 1 is a view illustrating an organic light emitting diode device according to an exemplary embodiment of the present invention;

[0014] FIG. 2 is a graph illustrating a current density according to a driving voltage of the organic light emitting diode device fabricated according to an exemplary embodiment of the present invention; and

[0015] FIG. 3 is a graph showing a life span deterioration ratio according to a time of according to the organic light emitting diode device fabricated according to an exemplary embodiment of the present invention.

DETAILED DESCRIPTION

[0016] Reference will now be made in detail to embodiments of the invention, examples of which are illustrated in the accompanying drawings. Wherever possible, the same reference numbers will be used throughout the drawings to refer to the same or like parts. It will be paid attention that detailed description of known arts will be omitted if it is determined that the arts can mislead the embodiments of the invention.

[0017] FIG. 1 is a view illustrating an organic light emitting diode device according to an exemplary embodiment of the present invention. Hereinafter, an organic light emitting diode device in which two stacks are laminated is described by way of example, but the present invention is not limited thereto.

[0018] Referring to FIG. 1, the organic light emitting diode device 100 according to an exemplary embodiment of the

present invention may be a white organic light emitting diode device having yellow and blue lights. In detail, the organic light emitting diode device **100** includes a first electrode **120** on a substrate **110**, a first stack **130** disposed on the first electrode **120** and including a first emission layer **133**, a charge generation layer **140** disposed on the first stack **130**, a second stack **150** disposed on the charge generation layer **140** and including a second emission layer **153**, and a second electrode **160** disposed on the second stack **150**.

[0019] The substrate **110** may be made of transparent glass and plastic material, or conductive material. The first electrode **120** is an anode electrode injecting a hole and may be a transparent electrode transmitting light. The first electrode **120** is configured by one of Indium Tin Oxide (ITO), Indium Zinc Oxide (IZO), or Zinc Oxide (ZnO). The organic light emitting diode device **100** may include a protective layer **115** between the substrate **110** and the first electrode **120**. The protective layer **115** reflects light upward and may be made of one aluminum (Al), silver (Ag), and nickel (Ni) at a lower portion of the first electrode **120**.

[0020] The first stack **130** disposed on the first electrode **120** may include a first emission layer **133** emitting blue light. The first stack **130** may include only a blue emission layer as the first emission layer **133** and emit blue light to increase color stability of blue. The first emission layer **133** is an emission layer emitting blue light, and a fluorescent blue dopant may be mixed with one host. For example, the first emission layer **130** may be formed by mixing 1,6-Bis(diphenylamine)pyrene or TBPe(tetrakis(t-butyl)perylene) being a fluorescent blue dopant with a host material such as AND(9,10-di(2-naphthyl)anthracene) or DPVBi(4,4'-bis(2,2-diphenylethen-1-yl)-diphenyl). The fluorescent blue dopant may be a deep or sky blue dopant. For example, the deep blue dopant may include 4'-N,N-diphenylaminostyryl-triphenyl (DPA-TP), 2,5,2',5'-tetrastyl-biphenyl (TSB), or anthracene derivative.

[0021] For example, the sky blue dopant may include p-bis(p-N,N-diphenyl-aminostyryl) benzene or phenyl cyclopentadiene.

[0022] The first stack **130** may further include a first hole injecting layer (HIL) **131** formed between the first electrode **120** and the first emission layer **133**, and a first electron transport layer (HTL) **134** formed between the first emission layer **133** and the charge generation layer **140**.

[0023] The first HIL **131** may easily inject a hole from the first electrode **120** to the first emission layer **133**. The first HIL **131** may be made of at least one selected from the group consisting of copper phthalocyanine (CuPc), poly(3,4)-ethylenedioxythiophene (PEDOT), polyaniline (PANI), and N,N-dinaphthyl-N,N'-diphenyl benzidine (NPD), but the present invention is not limited thereto.

[0024] The first HTL **132** functions to easily transport a hole. The first HTL **132** may be made of at least one selected from the group consisting of N,N-dinaphthyl-N,N'-diphenyl benzidine (NPD), N,N'-bis-(3-methylphenyl)-N,N'-bis-(phenyl)-benzidine (TPD), s-TAD, and (4,4',4''-Tris(N-3-methylphenyl-N-phenyl-amino)-triphenylamine (MTDATA), but the present invention is not limited thereto.

[0025] The first electron transport layer (ETL) **134** functions to easily transport an electron. The first ETL **134** may be made of at least one selected from the group consisting of tris(8-hydroxyquinolino)aluminum (Alq3), PBD, TAZ, spiro-PBD, BAlq, and SAiq, but the present invention is not limited thereto.

[0026] Meanwhile, a charge generation layer (CGL) **140** disposed on the first stack **130** is a PN junction charge generation layer where a junction is formed between an N type charge generation layer **141** and a P type charge generation layer **142**. The PN junction CGL **140** generates and injects the charge to the respective emission layers or separately injects a hole and an electron into each emission layer. That is, the N type CGL **141** supplies an electron to the first emission layer **133** adjacent to the first electrode **120** and the P type CGL **142** supplies a hole to the second emission layer **153** adjacent to the second electrode **160**, so that luminous efficiency of the organic light emitting diode device including a plurality of emission layers may be increased and a driving voltage may be reduced.

[0027] The N type CGL **141** is made of pyrene compound, and a detailed description thereof will be described below. The P type CGL **142** may be made of metal or an organic material doped with a P type dopant. Here, the metal may include one selected from the group consisting of Al, Cu, Fe, Pb, Zn, Au, Pt, W, In, Mo, Ni, and Ti, and an alloy thereof. A P type dopant and a host material used in an organic material doped with the P type dopant may use a generally used material. For example, the P type dopant may be one material selected from the group consisting of 2,3,5,6-tetrafluoro-7,7,8,8-tetracyanoquinodimethane (F4-TCNQ), a derivative of tetracyanoquinodimethane, iodine, FeCl₃, FeF₃, and SbCl₅. Further, the host may be one material selected from the group consisting of N,N'-D(naphthalene-1-1)-N,N-diphenyl-benzidine (NPB), N,N'-diphenyl-N,N'-bis(3-methylphenyl)-1,1-biphenyl-4,4'-diamine (TPD), and N,N',N'-tetranaphthyl-benzidine (TNB).

[0028] The second stack **150** disposed on the CGL **140** may include the second emission layer **153** emitting yellow light. The second emission layer **153** may include a yellow dopant in a host or red and green dopants in one host.

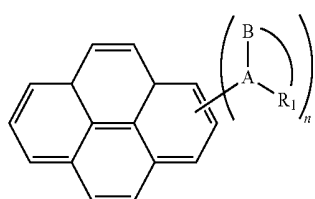
[0029] For example, when the second emission layer **153** includes the yellow dopant in the host, the second emission layer **153** may use the same material as that of the host of the first emission layer **133** as the host and a blue dopant, and may use Irpq2acac(bis(phenylquinoline) iridium acetylacetonate). Further, when the second emission layer **153** includes red and green dopants in one host, Ir(piq)2acac(bis(phenylisoquinoline) iridium acetylacetonate) may be used in the foregoing host as a red phosphoresce dopant. An Irppy3(tris(phenylpyridine) iridium) may be used as the red phosphoresce dopant.

[0030] The second stack **150** may further include a second hole injection layer **151** and a second hole transport layer **153** formed between the CGL **140** and the second emission layer **153**, and a second electron transport layer **154** and an electron injection layer (EIL) **155**. The second hole injection layer **151**, the second hole transport layer **152**, and the second electron transport layer **154** have the same functions as those of the first hole injection layer **131**, the first hole transport layer **132**, and the first electron transport layer **134**, and thus the description thereof is omitted.

[0031] The EIL **155** functions to easily inject an electron, and may use Alq3(tris(8-hydroxyquinolino)aluminum), PBD, TAZ, spiro-PBD, BAlq, or SAiq, but the present invention is not limited thereto. In addition, the EIL **155** may be made of a metal halide compound. For example, the metal halide compound may be one selected from the group consisting of MgF₂, LiF, NaF, KF, RbF, CsF, FrF, and CaF₂, but the present invention is not limited thereto.

[0032] The second electrode (cathode) **160** may be made of a transparent material so that light emitted from the emission layers **133** and **135** may be outputted to a front surface. For example, the second electrode **160** may be made of one of indium tin oxide (ITO), indium zinc oxide (IZO), and zinc oxide (ZnO).

[0033] The N type CGL **141** of the present invention may be made of a pyrene compound represented as a following chemical formula 1.

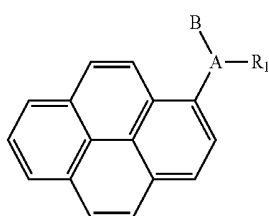


[Chemical formula 1]

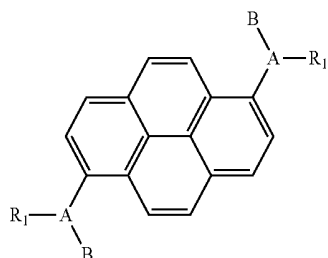
[0034] In the chemical formula 1, the A is one selected from C, N, S, and O, the B and R1 are one selected from a hetero aromatic group having 6 to 24 carbon atoms which includes or does not include a neighboring A, a substituted or unsubstituted aromatic arylamine group, or a substituted or unsubstituted hetero aromatic arylamine group, and the n is an integer in the range of 1 to 4.

[0035] The R1 neighboring the B including the A forms or does not form a fused ring.

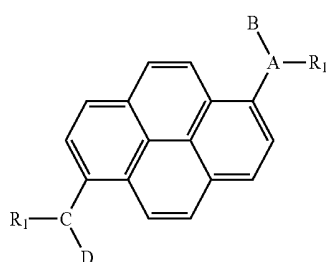
[0036] The chemical formula 1 is represented as following chemical formulas 2 to 8.



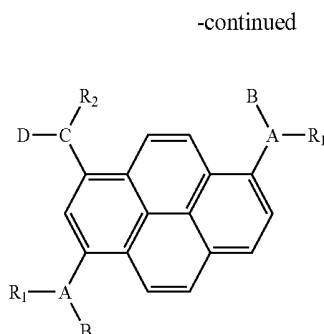
[Chemical formula 2]



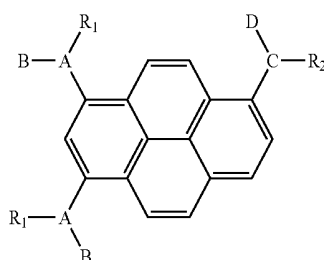
[Chemical formula 3]



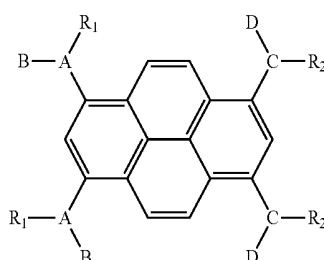
[Chemical formula 4]



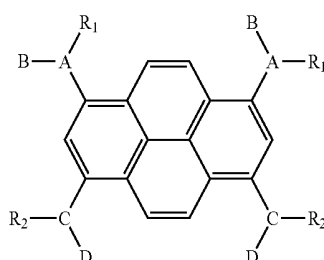
[Chemical formula 5]



[Chemical formula 6]



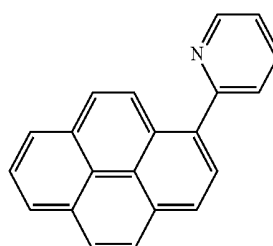
[Chemical formula 7]



[Chemical formula 8]

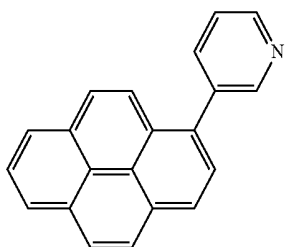
[0037] In the chemical formulas 2 to 8, each substituent may form a fused ring with a neighboring substituent.

[0038] The compound represented as the chemical formula 1 is expressed as compounds of following P1 to P26.



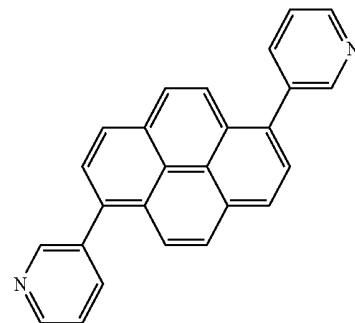
P1

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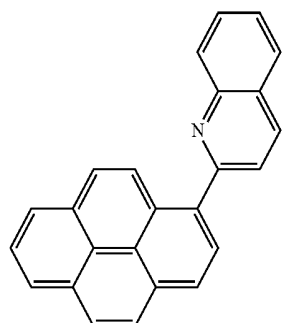


P2

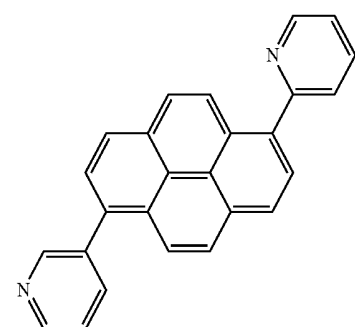
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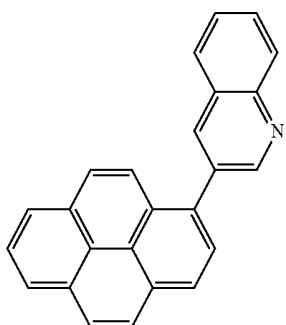
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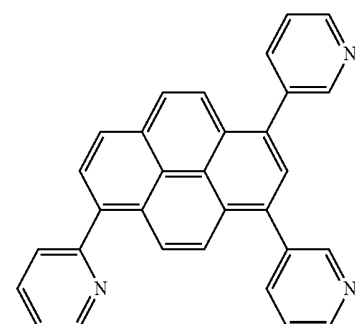
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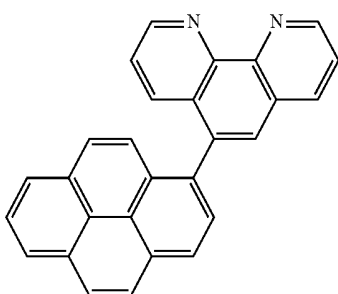
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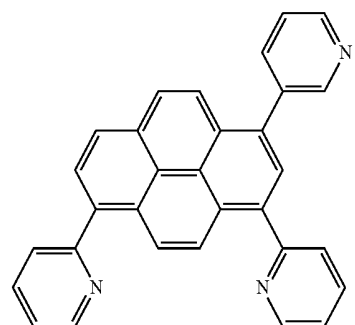
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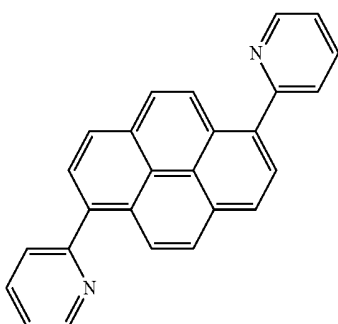
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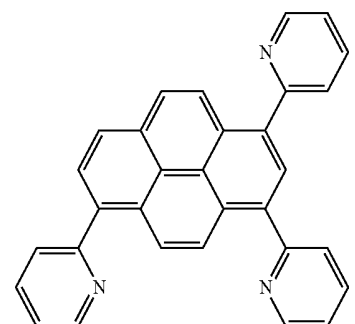
P5



P10

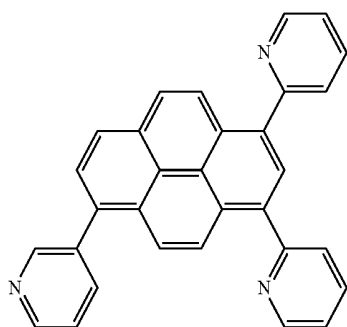


P6



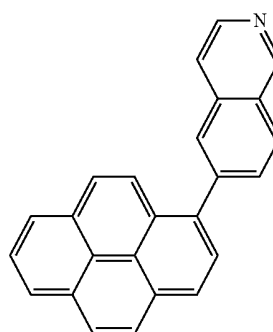
P11

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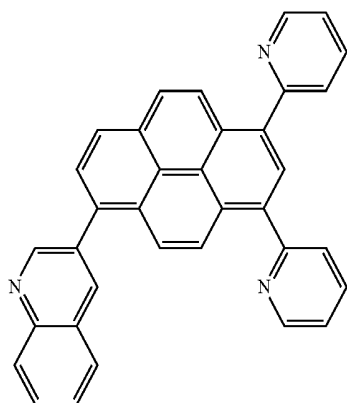


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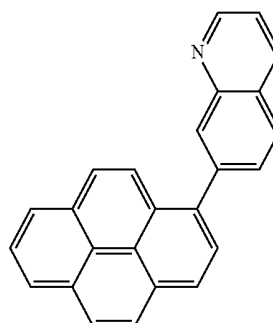
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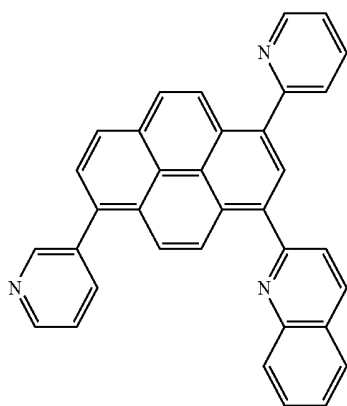
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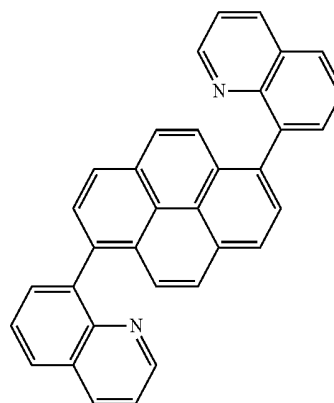
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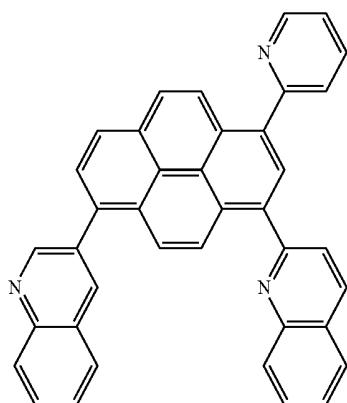
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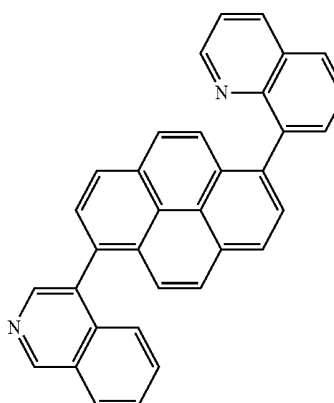
P14



P18

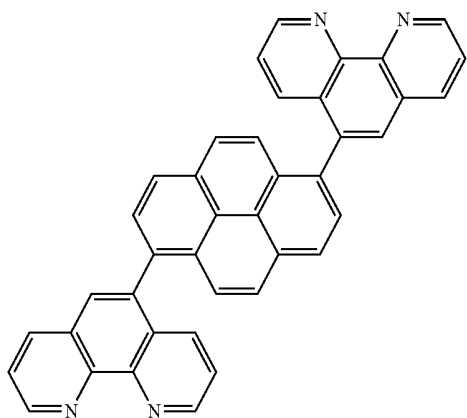


P15



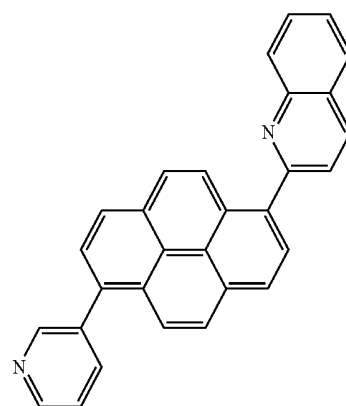
P19

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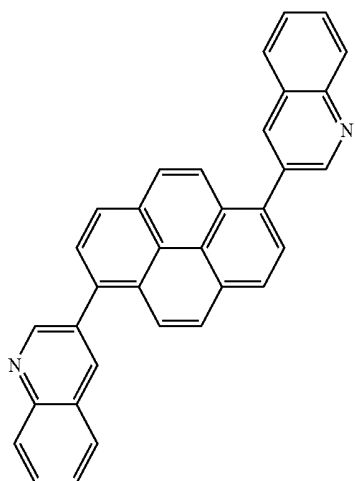


P20

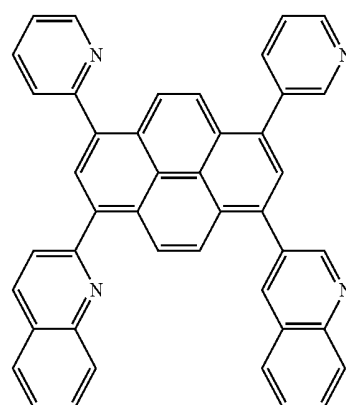
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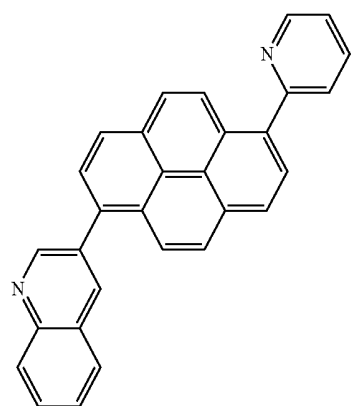
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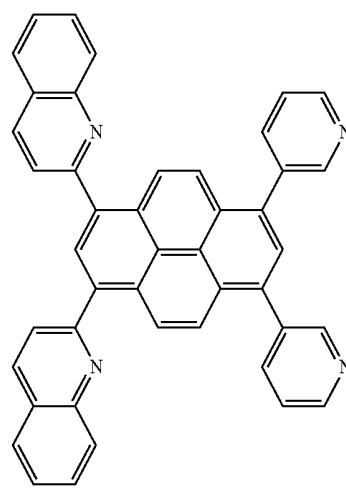
P21



P24



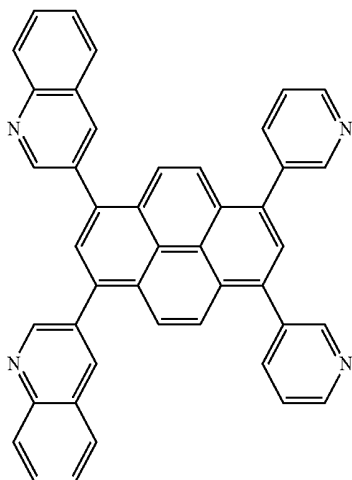
P22



P25

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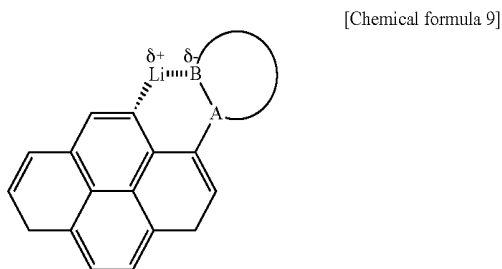
P26



[0039] At least one substituent in the chemical formula 1 is substituted in numbers 1, 3, 6, and 8 locations of a pyrene.

[0040] Since number 2 and 6 locations of the pyrene in the chemical formula 1 are easily substituted and there is a π interacted carbon in a beta location from a substituted location, an orbital associated with π interaction of the carbon may be used in interaction with transition metal.

[0041] In detail, referring to a following chemical formula 9, when lithium (Li) is doped with an N type dopant, a site having a rich electron is positioned at a location B, so that the lithium (Li) doped with the N type dopant easily interacts with lithium being a system having a relatively deficient electron that enables stronger interaction while forming the chemically stablest hexagonal ring shape. In this case, a location A directly donates the electron or functions a linker of donating.

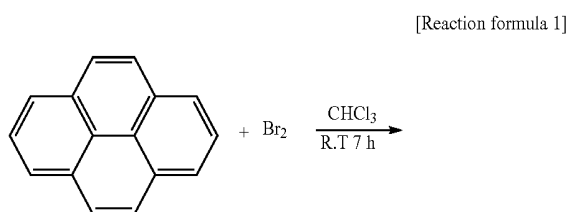


[0042] Hereinafter, a synthesis example of the pyrene compound used for the N type CGL of the present invention and the organic light emitting diode device including the same will be described with reference to a following synthesis example and embodiment. However, embodiments will be described by way of example only, and the present invention is not limited to following embodiments.

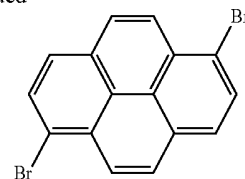
SYNTHESIS EXAMPLE

1) Synthesis of 2,4-dibromo-9-phenyl-9H-carbazole(B)

[0043]



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Prepared Example

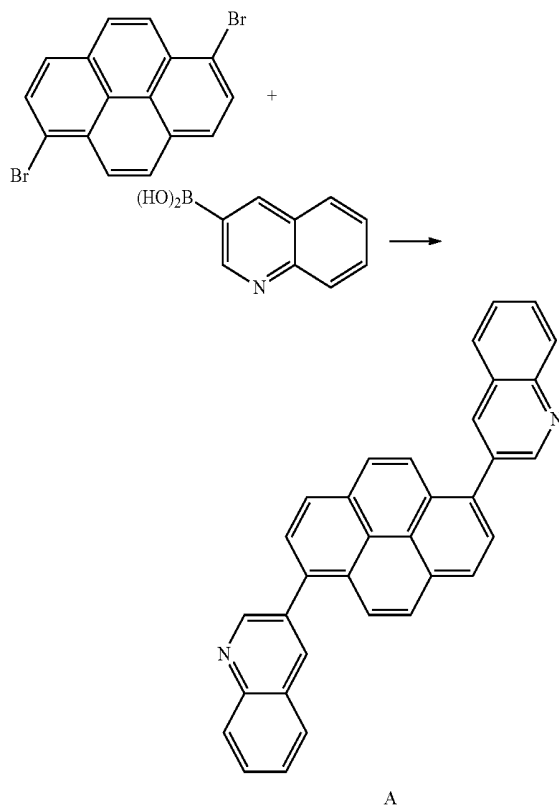
Synthesis of Dibromo Pyrene

[0044] A first solution including bromine 16 g and chloroform 100 ml was dropped in a second solution obtained by solving pyrene 10.0 g (49.4 mmol) in chloroform 250 ml while agitating the second solution at a temperature of 23°C. for 7 hours. After additionally agitating the second solution for one hour, an obtained reaction liquid (including crystal) was filtered so that a crystal was obtained. A dibromo pyrene 11.3 g is obtained by washing the crystal and then drying the washed crystal under reduced pressure (yield 63%) GC-Mass (theoretical value: 283.16 g/mol, measured value: 282 g/mol).

2) Manufacture of compound A: synthesis of 1,6-di(quinolin-3-yl)pyrene (A)

[0045]

[Reaction formula 2]



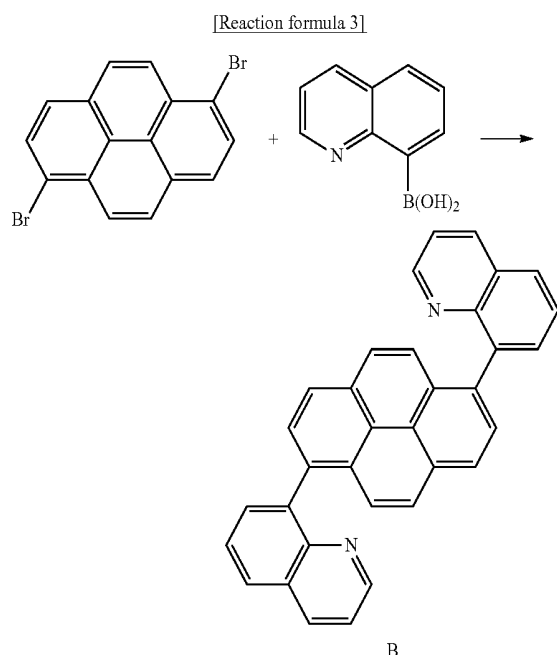
[0046] Quinoline-3-boronic acid (2.2 g, 12.2 mmol), triocetylammmonium chloride (trademark name: Aliquat336

(hereinafter referred to as 'Aliquat336'), prepared by Aldrich Corporation, 0.74 g), palladium acetate (1.3 mg), tris(o-methoxyphenyl)phosphine (13.3 mg), toluene (58 ml), and sodium carbonate water solution (17.8 mmol) were added to dibromo pyrene (2.0 g, 5.6 mmol) synthesized in the prepared example and they were agitated at a temperature of 100° C. of four hours. A crystal was obtained by cooling the resultant reaction liquid at room temperature and filtering the cooled reaction (including the crystal). The compound A of 1.2 g was obtained by washing the crystal in an order of toluene, water, and methanol, and drying the washed crystal under reduced pressure (yield 46%).

[0047] GC-Mass (theoretical value: 456.16 g/mol, measured value: 456 g/mol), ¹H-NMR (THF-d₈, 500 MHz) (ppm) 7.58 (m, 2H), 7.68~7.74 (m, 8H), 8.04~8.06 (m, 4H), 8.22 (m, 2H), 9.03 (m, 2H)

3) Manufacture of compound B: synthesis of 1,6-di(quinolin-8-yl)pyrene (B)

[0048]

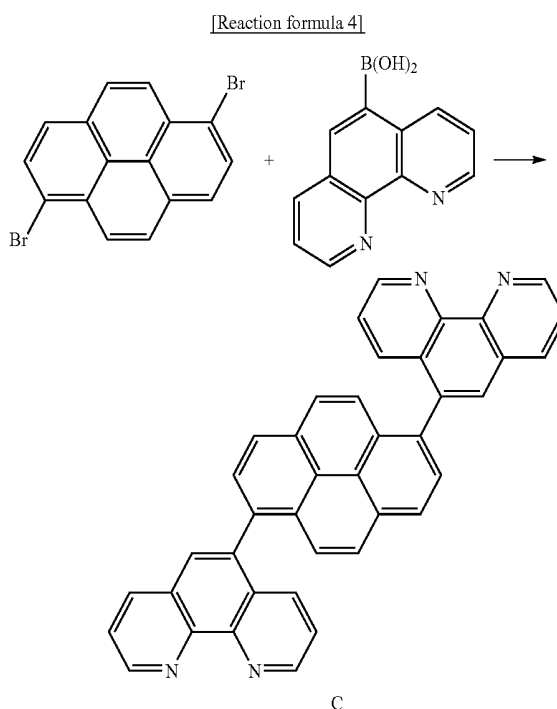


[0049] Quinoline-8-boronic acid (2.2 g, 12.2 mmol), triethylmethylammonium chloride (trademark name: Aliquat336 (hereinafter referred to as 'Aliquat336'), prepared by Aldrich Corporation, 0.74 g), palladium acetate (1.3 mg), tris(o-methoxyphenyl)phosphine (13.3 mg), toluene (58 ml), and sodium carbonate water solution (17.8 mmol) were added to dibromo pyrene (2.0 g, 5.6 mmol) synthesized in the prepared example and they were agitated at a temperature of 100° C. of four hours. A crystal was obtained by cooling the resultant reaction liquid at room temperature and filtering the cooled reaction (including the crystal). The compound B of 1.8 g was obtained by washing the crystal in an order of toluene, water, and methanol, and drying the washed crystal under reduced pressure (yield 48%).

[0050] GC-Mass (theoretical value: 456.16 g/mol, measured value: 456 g/mol), ¹H-NMR (THF-d₈, 500 MHz) (ppm) 7.49~7.71 (m, 10H), 7.83 (m, 2H), 8.00~8.06 (m, 6H), 8.81 (m, 2H)

4) Manufacture of compound C: synthesis of 1,6-di(1,10-phenanthroline-5-yl)pyrene (C)

[0051]



[0052] 1,10-phenanthrene-5-boronic acid (2.2 g, 12.2 mmol), triethylmethylammonium chloride (trademark name: Aliquat336 (hereinafter referred to as 'Aliquat336'), prepared by Aldrich Corporation, 0.74 g), palladium acetate (1.3 mg), tris(o-methoxyphenyl)phosphine (13.3 mg), toluene (58 ml), and sodium carbonate water solution (17.8 mmol) were added to dibromo pyrene (2.0 g, 5.6 mmol) synthesized in the prepared example and they were agitated at a temperature of 100° C. of four hours. A crystal was obtained by cooling the resultant reaction liquid at room temperature and filtering the cooled reaction (including the crystal). The compound C of 2.4 g was obtained by washing the crystal in an order of toluene, water, and methanol, and drying the washed crystal under reduced pressure (yield 77%).

[0053] GC-Mass (theoretical value: 558.63 g/mol, measured value: 558 g/mol), ¹H-NMR (THF-d₈, 500 MHz) (ppm) 7.26 (m, 2H), 7.55 (m, 2H), 7.71~7.77 (m, 6H), 8.00~8.06 (m, 8H), 8.80 (m, 4H)

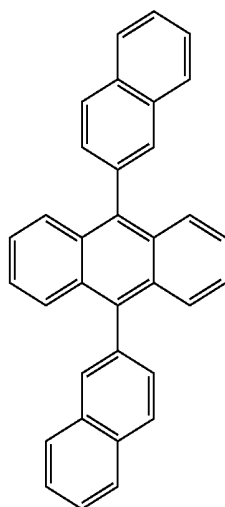
Comparative Example

[0054] Hereinafter, disclosed is an embodiment of fabricating an organic light emitting diode device using a pyrene compound prepared in the foregoing synthesis example as an N type CGL.

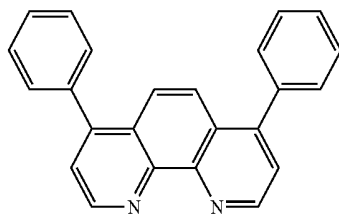
[0055] A layer structure of the embodiment is the same as that of the comparative example to be described below. The difference is that a host material of the N type CGL is compounds A, B, C and B-phen(4,7-diphenyl-1,10-phenanthroline). First, a first electrode was formed on a transparent substrate by indium tin oxide (ITO) being an anode material. N,N'-diphenyl-N,N'-bis-[4-(phenyl-m-tolylamino)-phenyl]-biphenyl-4,4'-diamine having a thickness of 10 nm is formed

on the first electrode to form a hole injection layer. NPD (4,4'-bis[N-(1-naphthyl)-N-phenylamino]-biphenyl) (N,N'-diphenyl-N-naphthyl-N'-biphenyl-1,1-biphenyl-4,4"-diamine) having a thickness of 100 nm was deposited on the hole injection layer to form a hole transport layer. An emission layer having a thickness of 200 Å including a fluorescent blue dopant in a fluorescent host material expressed in a following exemplary molecule 1 was formed on the hole transport layer. An electron transport layer was formed on the emission layer by depositing Alq3 having a thickness of 350 Å, and a CGL was formed on the electron transport layer. In this case, the CGL is divided into two layers which are an N type layer and a P type layer. The N type layer is formed by co-depositing B-phen(4,7-diphenyl-1,10-phenanthroline) expressed by a following exemplary molecule 2 and metal dopant lithium with a volume ratio of 1% to 50%. The P type was formed by depositing HAT-CN(dipyrazino[2,3-f:2',3'-h]quinoxaline-2,3,6,7,10,11-hexacarbonitril) represented as a following exemplary molecule 3 having a thickness of 100 Å. Finally, a second electrode as a cathode was formed on the CGL by using protective metal such as Al.

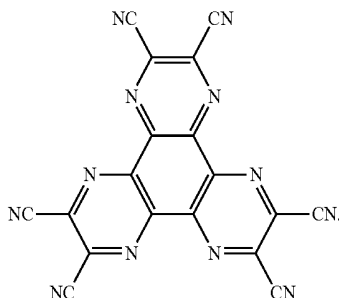
<Exemplary molecule 1>



<Exemplary molecule 2>



<Exemplary molecule 3>



Example 1

[0056] Under the same process conditions as those of the comparative example, an N type CGL is formed using the foregoing prepared compound A instead of B B-phen(4,7-diphenyl-1,10-phenanthroline) represented as the exemplary molecule 2.

Example 2

[0057] Under the same process conditions as those of the comparative example, an N type CGL is formed using the foregoing prepared compound B instead of B B-phen(4,7-diphenyl-1,10-phenanthroline) represented as the exemplary molecule 2.

Example 3

[0058] Under the same process conditions as those of the comparative example, an N type CGL is formed using the foregoing prepared compound C instead of B B-phen(4,7-diphenyl-1,10-phenanthroline) represented as the exemplary molecule 2.

[0059] Driving voltages, current efficiencies, quantum efficiencies, color coordinates, and life spans of the organic light emitting diode device according to the first to third embodiments and the comparative example are measured and listed in a following table 1. Further, current densities according to driving voltages are measured and illustrated in FIG. 2, and a deterioration rate of luminance according to a time is measured and illustrated in FIG. 3.

TABLE 1

	Driving voltage	Current effi- ciency	Quan- tum efficien-	Color coordinates		Life span
	(V)	(cd/A)	cy (%)	CIE_x	CIE_y	(T80, hr)
Example 1	6.0	6.8	7.4	0.135	0.105	220
Example 2	6.6	6.8	7.6	0.135	0.102	190
Example 3	6.3	6.6	7.1	0.135	0.106	80
Comparative example	5.9	6.6	7.0	0.134	0.109	160

[0060] As listed in the table 1, it will be appreciated that the organic light emitting diode device fabricated according the first to third embodiments of the present invention can significantly improve quantum efficiency while representing color coordinates of the same level as that of the comparative example. Particularly, referring to FIG. 2, the current density according to the driving voltage is improved, and a life span characteristic is significantly improved as shown in FIG. 3.

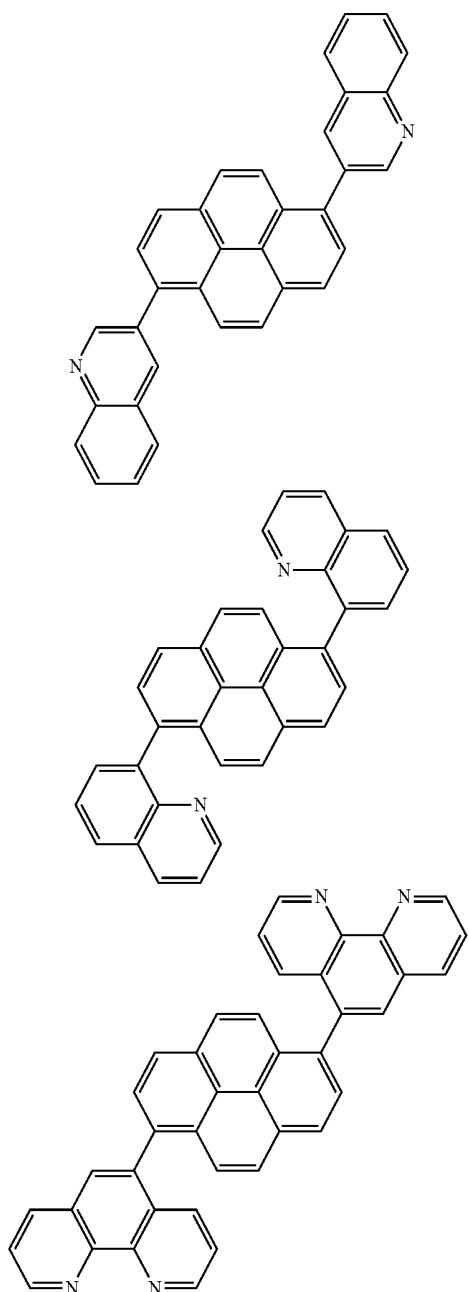
[0061] Therefore, the pyrene compound and the organic light emitting diode device including the same according to the embodiment of the present invention can improve the quantum efficiency and the life span characteristic as compared with an organic light emitting diode device according to the related art.

[0062] Although embodiments have been described with reference to a number of illustrative embodiments thereof, it should be understood that numerous other modifications and embodiments can be devised by those skilled in the art that will fall within the scope of the principles of this disclosure. More particularly, various variations and modifications are possible in the component parts and/or arrangements of the

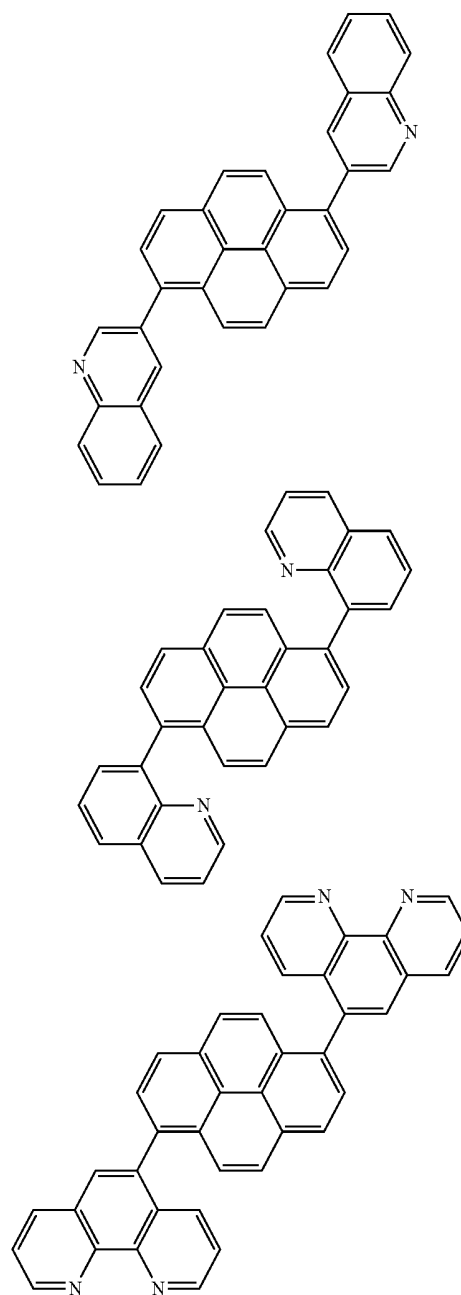
subject combination arrangement within the scope of the disclosure, the drawings and the appended claims. In addition to variations and modifications in the component parts and/or arrangements, alternative uses will also be apparent to those skilled in the art.

What is claimed is:

1. A pyrene compound represented by one of the following compounds:



2. An organic light emitting diode device comprising:
at least two stacks provided between a first electrode and a second electrode; and
a charge generation layer provided between the stacks and including an N type charge generation layer and a P type charge generation layer,
wherein the N type charge generation layer is made of the pyrene compound represented by one of the following compounds:



3. The organic light emitting diode device of claim 2, wherein each of the stacks comprises a hole injection layer and a hole transport layer formed at one side of the stack and an electron transport layer formed at an opposite side of the stack, while being interposed an emission layer therebetween.

4. The organic light emitting diode device of claim 2, wherein stacks adjacent to the second electrode among the stacks further comprise an electron injection layer.

5. The organic light emitting diode device of claim 2, wherein emission layers of the stacks emit lights of different colors, respectively.

6. The organic light emitting diode device of claim 2, wherein the N type charge generation layer is doped with alkaline metal.

* * * * *

专利名称(译)	芘化合物和包括其的有机发光二极管器件		
公开(公告)号	US20150357577A1	公开(公告)日	2015-12-10
申请号	US14/831638	申请日	2015-08-20
[标]申请(专利权)人(译)	乐金显示有限公司		
申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
当前申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
[标]发明人	KIM SHINHAN SEO JEONGDAE KIM HYOSEOK JUNG YOUNGKWAN JEON EUNJU		
发明人	KIM, SHINHAN SEO, JEONGDAE KIM, HYOSEOK JUNG, YOUNGKWAN JEON, EUNJU		
IPC分类号	H01L51/00 C07D519/00 C07D215/12		
CPC分类号	H01L51/0054 C07D215/12 H01L51/0072 C07D519/00 H01L51/5206 H01L51/5036 H01L51/5088 H01L51/5056 H01L51/5072 H01L51/5092 H01L51/5221 C07D213/06 C07D213/16 C07D215/04 C07D401/10 C07D401/14 C07D471/04 C09B57/001 H01L27/3211 H01L51/0052 H01L51/0058 H01L51/0067 H01L51/5012 H01L51/5044 H01L51/5278		
优先权	1020120097357 2012-09-03 KR		
其他公开文献	US9793489		
外部链接	Espacenet USPTO		

摘要(译)

公开了芘化合物和包含其的有机发光二极管装置。有机发光二极管装置包括设置在第一电极和第二电极之间的至少两个堆叠，以及设置在堆叠之间并且包括N型电荷产生层和P型电荷产生层的电荷产生层，其中N型电荷产生层由芘化合物制成。

